



EVAL6520-1421

14 W / 21 W T5 miniature ballast driven by L6520
and STT13005D bipolar transistors

Data brief

Features

- Drives either T5-14W-HE or T5-21W-HE lamps
- Standard form factor (19 mm x 120 mm)
- Compliance with IEC61347-2-3, IEC61000-2-3 and EN55022 Class-C

Description

The EVAL6520-1421 is a demonstration board able to drive either a 14 W or 21 W linear T5 fluorescent lamp with the L6520 low voltage ballast controller.

The half bridge consists of NPN high voltage power transistors driven by a suitable pulse transformer.



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1 Introduction

The L6520 low voltage ballast controller is intended to drive extremely compact applications based on either MOSFETs or bipolar transistors.

The EVAL6520-1421 is capable of driving either a T5-14W-HE or T5-21W-HE lamp, with the same miniaturized (16 mm wide) ballast.

The selection of both the resonant components and the bipolar transistors, together with the design of the suitable pulse transformer, and IC power supply is also described.

2 Board description

The board is supplied by any AC voltage in the European mains range and does not need any power factor correction having an input power of less than 25 W.

The half bridge voltage is obtained by filtering the rectified input voltage. This allows the use of a cheaper bulk capacitor and bipolar transistors.

The selection of a target condition is required by the range of the input voltage together with the necessity to drive two different kinds of lamps. In particular, the best driving condition and the best efficiency is obtained at 240 Vac with a 14 W lamp connected.

An EMI filter is placed at the board's input to meet IEC61000 standards.

The lamp's cathodes are current preheated to make the ballast choke more compact thanks to the absence of auxiliary windings.

The resonant network design starts from the selection of the resonant capacitor (C10) that corresponds to the desired ballast efficiency. The inductance (L1) can be obtained by the following equation:

Equation 1

$$V_{\text{Lamp}} = \left| \frac{\frac{1}{R_{\text{Lamp}}}}{\frac{1}{R_{\text{Lamp}}} + j\omega C_{\text{RES}}} \cdot \frac{V_{\text{HB}}}{j\omega L_{\text{RES}} + \frac{1}{\frac{1}{R_{\text{Lamp}}} + j\omega C_{\text{RES}}}} \right|$$

V_{HB} is the effective voltage obtained across the half bridge along one mains cycle. The lower voltage is obtained at 50 Hz and can be approximately computed as:

Equation 2

$$V_{\text{HB}} = \left(\frac{\sqrt{2}}{2} \cdot V_{\text{IN}} - V_{\text{F}} \right) + \sqrt{\left(\frac{\sqrt{2}}{2} \cdot V_{\text{IN}} - V_{\text{F}} \right)^2 - \frac{1.54 \cdot 10^5 \cdot P_{\text{LAMP}}}{f_{\text{MAINS}} \cdot C_{\text{OUT}}}}$$

where:

- V_{F} is the forward voltage drop of the rectifier bridge (1 V typ.)
- V_{IN} is the RMS value of the input voltage
- C_{OUT} is the value of the bulk capacitor in μF (In this case $C3 = 4.7 \mu\text{F}$ has been selected)

A resonant capacitor equal to 3.9 nF has been selected and resonant inductor equal to 3 mH has been calculated.

It is now possible to estimate the ignition frequency, which must be higher than 46 kHz (minimum programmable value), and the minimum preheating frequency that guarantees a preheating voltage higher than 130 Vrms, as required by the lamp specifications.

Equation 3

$$V_{PH-IGN} = \left| \frac{\frac{V_{PFC} \cdot \sqrt{2}}{\pi} \cdot \frac{1}{j\omega C_{RES}}}{\frac{1}{j\omega C_{RES}} + j\omega L_{RES}} \right|$$

A preheating frequency equal to 70 kHz has been selected by connecting a 2.49 kΩ resistor (R5) between the FPRES pin and GND.

The half bridge is based on two STT13005D power bipolar transistors (Q1 and Q2). Both the high side and low side transistor are driven by a pulse transformer (T2).

To design this pulse transformer, the following parameters must be taken into account:

- Maximum available spacing on the PCB: this determines the core dimension.
- Maximum magnetizing current ($I_{mag,rms}$) on the primary side of the transformer: this current causes core losses to not be transferred as a useful signal on the secondary side of the transformer. To minimize it, a higher primary inductance should be adopted. Typical inductances are between 6 mH and 40 mH, depending on the core dimension and the core permeability.
- Primary to secondary transfer ratio (n): the output voltage of a step-down transformer is lower than the input voltage, whereas the output current is higher than the input current. This helps to obtain higher DC currents with lower IC power dissipation. The minimum $V_{be(sat)}$ must be guaranteed in any condition as well as the minimum I_B that guarantees the saturation condition of the BJT.

The $I_{mag,rms(MAX)}$ is selected lower than 10 mA when V_{cc} is equal to 13 V and a typical storage time of 1.2 μs is considered, therefore the primary inductance must be:

Equation 4

$$L_{pri} \geq V_{cc} \cdot \frac{T_{on,max}}{I_{mag,rms}} = \sqrt{3} \cdot V_{cc} \frac{\frac{1}{2 \cdot f_{run}} - T_{dt} - T_{sto} - 200ns}{I_{mag,rms}} = 1.732 \cdot V_{cc} \frac{9.42\mu s - T_{sto}}{I_{mag,rms}} = 6.18mH$$

The V_{be} of the bipolar transistor can be calculated as follows (see [Figure 2](#)):

Equation 5

$$V_{be} = V_{pri} \cdot n - I_b \cdot R_b = \left[V_{cc} - \frac{I_b}{n} \cdot (R_{ds,on_h} + R_{pri} + R_{ds,on_l}) \right] \cdot n - I_b \cdot R_b$$

The R_{ds,on_h} and the R_{ds,on_l} are the ON resistances of the L6520 drivers and can be considered equal to 10 Ω each.

I_b is equal to I_c/h_{fe} , and can be considered equal to $I_c/6$. I_b times R_b can be set between 0.7 V and 1 V, during run mode: in this design R_b (R6 and R8) can be selected between 10 Ω and 13 Ω.

With these constraints the following is obtained:

Equation 6

$$V_{be} = \left[13 - \frac{0.46}{n} \cdot (20 + R_{pri}) \right] \cdot n - 0.76 = 13 \cdot n - 9.2 - 0.46 \cdot R_{pri} - 0.76 > 1.1 \rightarrow 13 \cdot n - 0.46 \cdot R_{pri} > 11.6$$

Selecting an R_{pri} (R7) equal to 47 Ω , the minimum transfer ratio should be equal to 2.55.

$n = 5.6$ has been selected.

The PWM_det pin network is composed of 3x220 k Ω resistors (R11 to R13) together with a 47 pF speed-up capacitor (C11). The value of the speed-up capacitor also avoids a misdetection of the hard switching.

During normal operation the IC absorbs the following currents from the Vcc:

1. Effective base currents of the BJTs divided by n (5.6). A 39 mA_(MAX) is estimated.
2. Magnetizing current = 10 mA_(MAX)
3. L6520 power consumption: 8 mA_(MAX)

A maximum current of 57 mA_{rms} must be foreseen. For this reason, the IC power supply has been connected in series with the resonant network (D4 and D5). This connection does not interfere with the optimum preheating of the lamp's cathodes, but introduces a little offset (7.5 V typ.) into the lamp voltage.

This offset affects the EOL detection, but a different choice of values of the Zener diodes (D6 and D7) makes the detection symmetrical. The two values, together with the resistance values (R14 and R15), can be calculated through the following system of equations ($V_{Lamp,MAX} = 30$ V and $V_{Lamp,min} = -16$ V):

Equation 7

$$\begin{cases} V_{Lamp,MAX} = V_{EOL} + V_{Z,D7} + I_{BIAS} \cdot (R14 + R15) + V_{F,D6} \\ V_{Lamp,min} = V_{EOL} - V_{Z,D6} - I_{BIAS} \cdot (R14 + R15) - V_{F,D7} \end{cases}$$

Finally, a 4.7 μ F is used as the Vcc bulk capacitor (C4) and two 100 nF ceramic capacitors (C5) are placed close to the Vcc pins of the two ICs.

By allowing the startup network (R2 to R4) to pass through the upper cathode of the lamp, the automatic re-lamp feature is easily obtained.

3 Board performance

Figure 1. EMI spectrum at nominal input voltage (230 Vac)

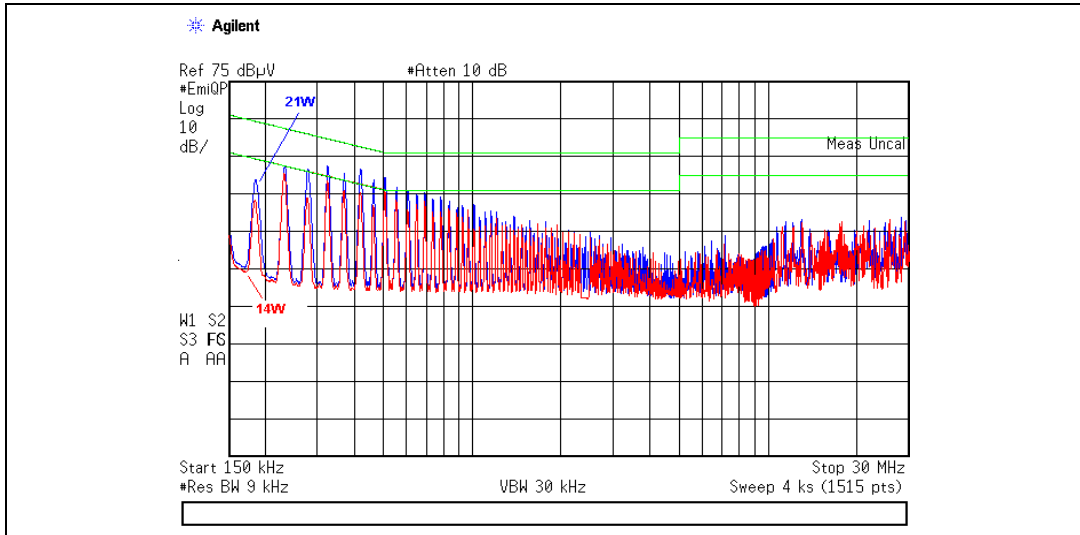


Figure 2. Lamp voltage and current (T5 14 W HE)

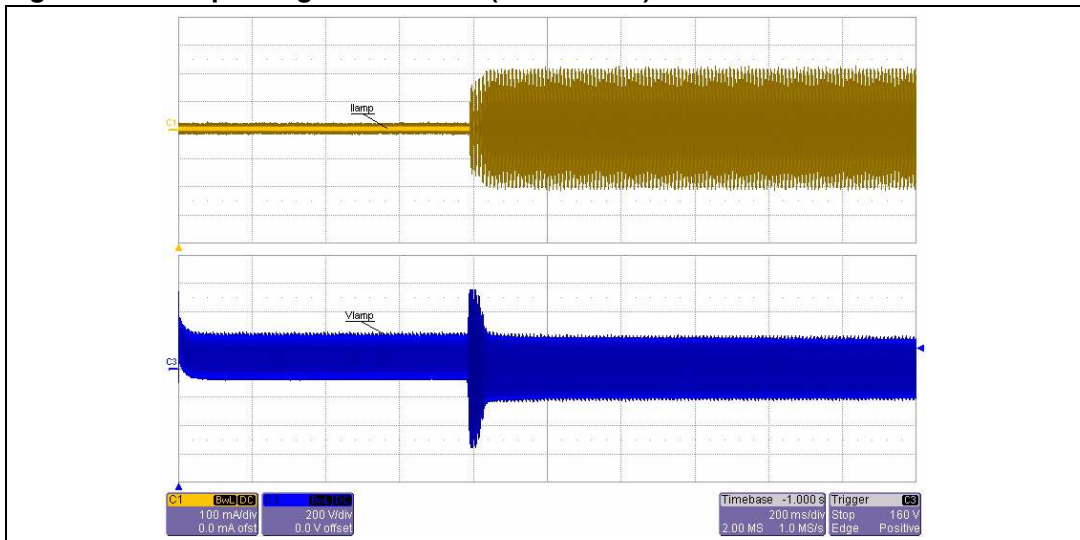
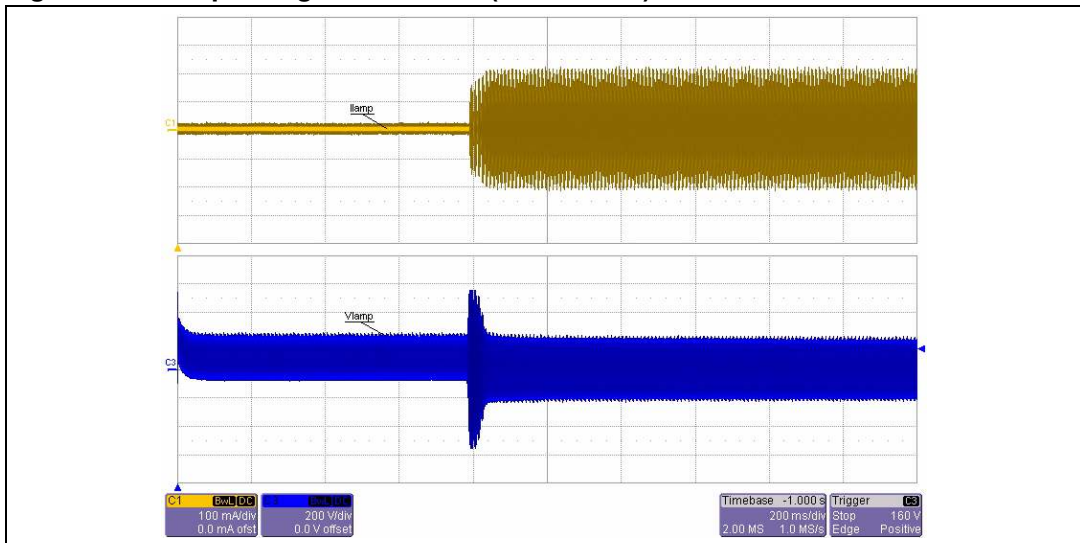


Figure 3. Lamp voltage and current (T5 21 W HE)



4 Application specifications

[Table 1](#) and [Table 2](#) show the application specifications for the input and lamp requirements.

Table 1. Input requirements

| Parameter | Value | Unit |
|---------------|------------|------------------|
| Input voltage | 198 to 264 | V _{rms} |
| Mains freq. | 50 to 60 | Hz |
| Input power | 25 | W max |

Table 2. Lamp requirements

| Parameter | T5 - 14 W | T5 - 21 W | Unit |
|-------------------------|-----------|-----------|-------------------|
| Lamp current | 170 ± 30% | | mA _{rms} |
| Lamp voltage | 82 ± 6% | 123 ± 6% | V _{rms} |
| Max. ignition voltage | 1000 | | V _{pk} |
| Max. preheating voltage | 130 | | V _{rms} |

5 Bill of material and board schematics

Table 3. Bill of material

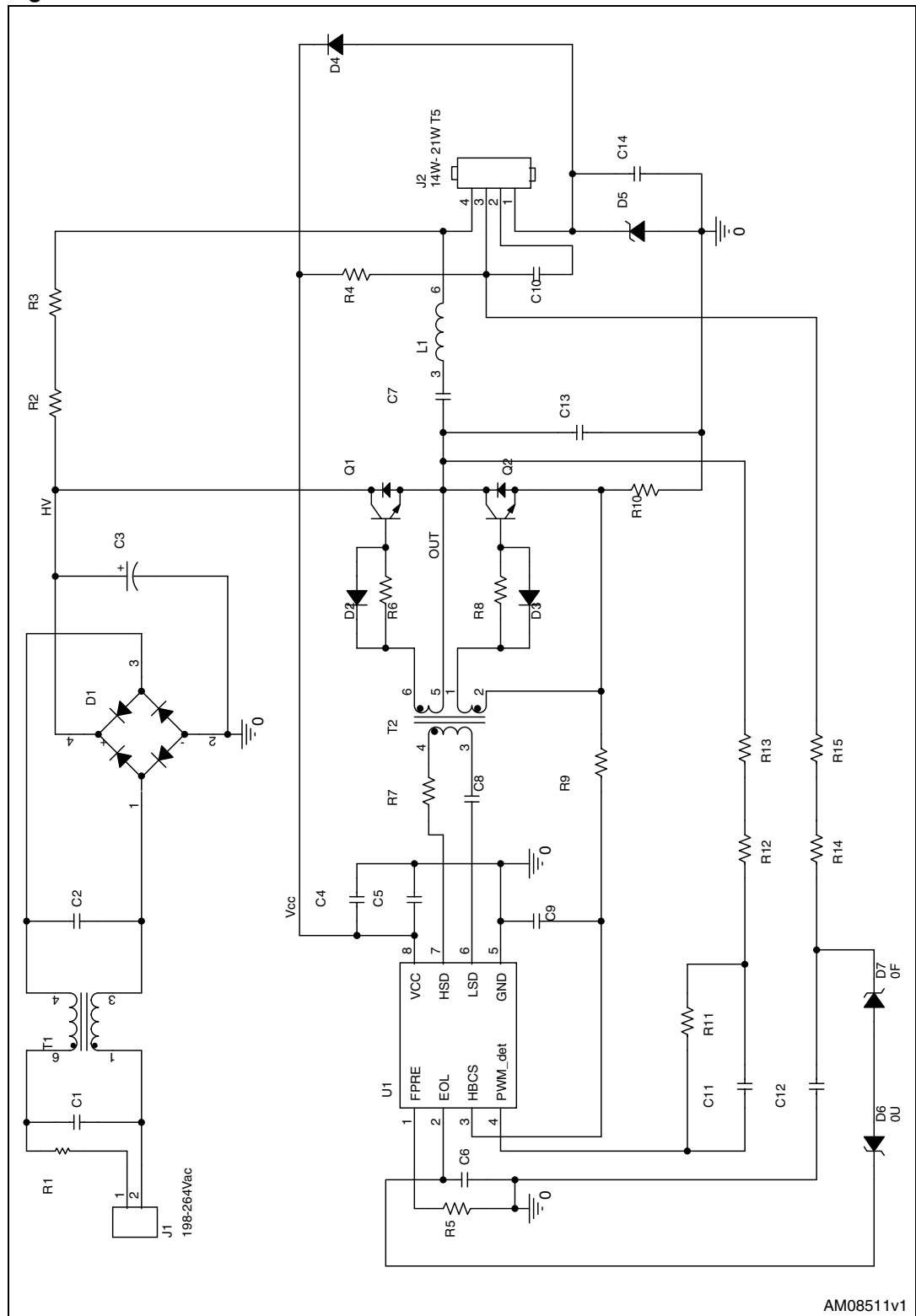
| Reference | Value / part number | Rating | Notes |
|-----------|---------------------|------------------|--------------------------|
| C1 | 100 nF | 275 Vac | |
| C2 | 100 nF | 275 Vac | |
| C3 | 4.7 μ F | 400 Vdc - 105 °C | |
| C4 | 4.7 μ F | 50 Vdc | |
| C5 | 100 nF | 25 Vdc | |
| C6 | 1 nF | 25 Vdc | |
| C7 | 100 nF | 400 Vdc | |
| C8 | 100 nF | 25 Vdc | |
| C9 | 1 nF | 25 Vdc | |
| C10 | 3.9 nF | 1000 Vdc | Panasonic ECQ P6392JU |
| C11 | 10 pF | 500 Vdc | |
| C12 | 100 nF | 25 Vdc | |
| C13 | Not mounted | | |
| C14 | 22 nF | 50 Vdc | |
| R1 | PCB fuse | 6 A - 1 s | |
| R2 | 330 k Ω | | |
| R3 | 330 k Ω | | |
| R4 | 270 k Ω | | |
| R5 | 2.94 k Ω | 0.1% | |
| R6 | 10 Ω | | |
| R7 | 47 Ω | | |
| R8 | 10 Ω | | |
| R9 | 470 Ω | | |
| R10 | 1.2 Ω | 1% | |
| R11 | 220 k Ω | | |
| R12 | 220 k Ω | | |
| R13 | 220 k Ω | | |
| R14 | 560 k Ω | | |
| R15 | 560 k Ω | | |
| T1 | 2 x 33 mH CM-filter | 440 mA / 250 Vac | SCLE16333-ITACOIL |

Table 3. Bill of material (continued)

| Reference | Value / part number | Rating | Notes |
|-----------|---------------------------|-------------|--|
| T2 | 5.6 : 1:1 | 12 mH | E0802-ITACOIL (Figure 5) |
| L1 | 3 mH | 0.9 A | E16113-ITACOIL (Figure 6) |
| U1 | L6520 | | |
| Q1 | STT13005D | | |
| Q2 | STT13005D | | |
| D1 | B6S-E3/80 | | |
| D2 | RB751V40T1 | | |
| D3 | RB751V40T1 | | |
| D4 | MMSD4148T1G | | |
| D5 | BZT03C15 | 3 W | |
| D6 | MM3Z6V8ST1 | 6.8 V Zener | |
| D7 | MM3Z6V8ST1 | 16 V Zener | |
| J1 | V _{IN} connector | 198-264 Vac | |
| J2 | Lamp connector | | |

5.1 Board schematic

Figure 4. Board schematic

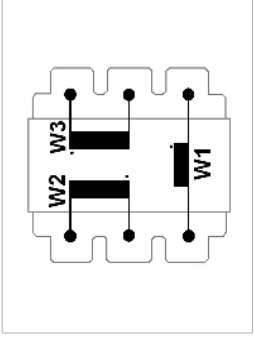


Appendix A Magnetic components data

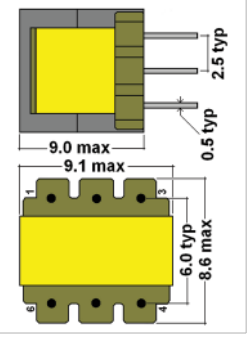
Figure 5. Pulse transformer (T2) datasheet

PRODUCT DATASHEET

| | | |
|--|--|--------------------------------|
| | CUSTOMER: ST Microelectronics Srl SAMPLING CODE: PRODUCT CODE: E0802 | |
| Temporary product description* BJT driver transformer | | L : 16,9mH min. (@10KHz-100mV) |
| W1 | 112 turns Ø0,08mm DCR: 6,6' +/-15% | |
| W2 | 20 turns Ø0,16mm DCR: 345 m' +/-15% | |
| 4 | 20 turns Ø0,16mm DCR: 365 m' +/-15% | |
| Dielectric strenght | 1000V/1sec. W1+W2+W3 / Core | |
| | 1000V/2sec. W1/W2+W3 | |
| Thermal class | B | |
| Bill of materials | Thermal Class | Standard |
| Magnet wire | T.I. 155°C (F) | EN60172 |
| Bobbin material | T.I. 130°C (B) - 20.000h | UL94/V-0 - IEC 60695 |
| Insulation tape | T.I. 130°C (B) | IEC 60112 |
| Varnish | T.I. 155°C (F) | |



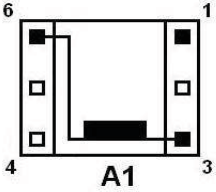
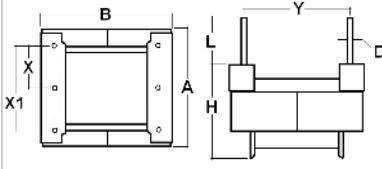
Layout (bottom view)



subject to change without notice

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Figure 6. Ballast choke (L1) datasheet

| PRODUCT DATASHEET | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|---|-----------------------|--|--|---|-------|-----|---|-------|-----|---|-------|-----|---|------|-----|----|------|-----|---|-------|-----|---|------|-------|---|------|-----|
| PRODUCT - REV | | E16113 | 00 | | | | | | | | | | | | | | | | | | | | | | | | |
| SAMPLING CODE | | 090710 | | | | | | | | | | | | | | | | | | | | | | | | | |
| PRODUCT DESCRIPTION ¹ | | Inductor 3.0 mH | | | | | | | | | | | | | | | | | | | | | | | | | |
| Thermal class | B | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Inductance | 3,0 mH +/-7% | | | | | | | | | | | | | | | | | | | | | | | | | | |
| DCR | 8,0 Ω max | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Rated current | 0,192A _{rms} | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Saturation current | > 0,65A _{pk} | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Max peak current | 0,85A _{pk} | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Dielectric strenght | 700Vac winding/core | | | | | | | | | | | | | | | | | | | | | | | | | | |
| LAYOUT (BOTTOM VIEW) | | DRAWING | DIMENSIONS (mm) | | | | | | | | | | | | | | | | | | | | | | | | |
|  | |  | <table border="1"> <tr> <td>A</td> <td>17,30</td> <td>MAX</td> </tr> <tr> <td>B</td> <td>17,20</td> <td>MAX</td> </tr> <tr> <td>H</td> <td>12,50</td> <td>MAX</td> </tr> <tr> <td>X</td> <td>3,80</td> <td>Typ</td> </tr> <tr> <td>X1</td> <td>7,60</td> <td>Typ</td> </tr> <tr> <td>Y</td> <td>12,50</td> <td>Typ</td> </tr> <tr> <td>D</td> <td>0,60</td> <td>Typ ∅</td> </tr> <tr> <td>L</td> <td>5,50</td> <td>Typ</td> </tr> </table> | A | 17,30 | MAX | B | 17,20 | MAX | H | 12,50 | MAX | X | 3,80 | Typ | X1 | 7,60 | Typ | Y | 12,50 | Typ | D | 0,60 | Typ ∅ | L | 5,50 | Typ |
| A | 17,30 | MAX | | | | | | | | | | | | | | | | | | | | | | | | | |
| B | 17,20 | MAX | | | | | | | | | | | | | | | | | | | | | | | | | |
| H | 12,50 | MAX | | | | | | | | | | | | | | | | | | | | | | | | | |
| X | 3,80 | Typ | | | | | | | | | | | | | | | | | | | | | | | | | |
| X1 | 7,60 | Typ | | | | | | | | | | | | | | | | | | | | | | | | | |
| Y | 12,50 | Typ | | | | | | | | | | | | | | | | | | | | | | | | | |
| D | 0,60 | Typ ∅ | | | | | | | | | | | | | | | | | | | | | | | | | |
| L | 5,50 | Typ | | | | | | | | | | | | | | | | | | | | | | | | | |
| COMPONENTS ² | | THERMAL CLASS | STANDARDS | | | | | | | | | | | | | | | | | | | | | | | | |
| Magnet wire | | T.I. 155°C (F) | EN60172 | | | | | | | | | | | | | | | | | | | | | | | | |
| Bobbin material | | T.I. 130°C (B) - 20.000h | UL94/V-0 - IEC 60695 | | | | | | | | | | | | | | | | | | | | | | | | |
| Insulation tape | | T.I. 130°C (B) | IEC 60112 | | | | | | | | | | | | | | | | | | | | | | | | |
| Varnish | | T.I. 155°C (F) | | | | | | | | | | | | | | | | | | | | | | | | | |
| <p>All the items, except those defined "safety transformers in compliance to the European standards EN61558-1 and EN61558-2-6" in our catalogue, are supplied as a semi-finished component for specific use into electronic equipments designed by the client. Type testing and any other valuation necessary to verify the compliance of the characteristics of the transformer with the technical, safety and any other requirement have to be done by the user, before using. Each requirement and test has to be requested in writing; without written instructions the product will be tested according to our Quality System standards.</p> <p>ST1 - ENG rev. 01 - 16/06/2010 subject to change without notice</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| <p>¹ Some data can be changed following type tests ² Only take into account materials actually present</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | |

AM07475v1

Revision history

Table 4. Revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 07-Mar-2011 | 1 | Initial release. |
| 28-Nov-2011 | 2 | Updated Section 2 and Table 3 . |

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